

1.2A, 30V Step Down DC/DC converter

NO.EA-293-111123

OUTLINE

The R1244N001B is CMOS-based Step-down DC/DC converter with an internal N-channel high side Tr. (R_{DSON} Typ. 0.35 Ω) power switch. The R1244N001B can provide the maximum 1.2A output current. The IC consists of an oscillator, a PWM control circuit, a reference voltage unit, an error amplifier, phase compensation circuits, a slope compensation circuit, a soft-start circuit, protection circuits, an internal voltage regulator, and a switch for a bootstrap circuit. To make a step-down DC/DC converter with the R1244N001B, as external components, an inductor, resistors, a diode, and capacitors are necessary.

The R1244N001B is a current mode PWM step-down DC/DC converter, but the external current sense resistor is not necessary. Fast transient response and high efficiency characteristics are realized with the R1244N001B. The R1244N001B allows the use of ceramic capacitors. The oscillator frequency is internally fixed at 1.25MHz.

Cycle by cycle current limit provides protection against over-current. Fold back circuit reduces frequency into 1/4 against shorted output and realizes limiting the Lx current. Thermal shutdown function and UVLO are also built-in.

FEATURES

	Operating Voltage 4.5V~30V
lacksquare	Internal Nch MOSFET Driver······Typ.Ron=0.35 Ω
lacksquare	Adjustable output voltage with external resistor 0.8V~15V
lacksquare	Feed back voltage ······ 0.8V±1.5%
lacksquare	Peak Current limit function Typ. 2.0A
lacksquare	UVLO function
lacksquare	Operating Frequency 1.25MHz (310kHz : fold condition)
lacksquare	Short protection for output Fold Back
lacksquare	Ceramic Capacitor compatible
lacksquare	Stand-by function
ullet	Package ······SOT-23-6W

APPLICATIONS

- Power source for digital home appliance
- Power source for hand-held communication equipment, cameras, video instruments such as VCRs, camcorders.
- Power source for battery-powered equipment.
- Battery Charger

BLOCK DIAGRAMS



SELECTION GUIDE

Product Name	uct Name Package Quantity per Reel		Pb Free	Halogen Free
R1244N001B-TR-FE	SOT-23-6W	3,000 pcs	Yes	Yes

PIN CONFIGURATION



PIN DESCRIPTION

• R1244N001B

Pin No.	Symbol	Description		
1	BST	Bootstrap Pin		
2	GND	Ground Pin		
3	Vfb	Feedback Pin		
4 CE Chip Enable Pin (Active with "H")				
5	VIN	Power Supply Pin		
6	Lx	Lx Switching Pin		

ABSOLUTE MAXMUM RATINGS

				(GND=0V)
Symbol	Item	Rating		Unit
VIN	Input Voltage	-0.3 to 32	2	V
VBST	BST Pin Voltage	VLX-0.3 to V	Lx +6	V
VLX	Lx Pin Voltage	-0.3 to V _{IN} +0.3		V
Ilx	Lx Pin Current	2		Α
Vce	CE Pin input Voltage	-0.3 to V _{IN} +0.3		V
Vfb	V _{FB} Pin Voltage	-0.3 to 4		V
PD	Power Dissipation(SOT-23-6W)	Standard Land Pattern 430 [*]		mW
Ta	Operating Temperature Range	-40 to 85		°C
Tstg	Storage Temperature Range	-55 to 125		°C

*) For Power Dissipation, please refer to PACKAGE INFORMATION.

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

ELECTRICAL CHARACTERISTICS

(Otherwise notified in Conditions, Vi⊧ 12					V, 1a=25°C	
Symbol	Item	Conditions	MIN.	TYP.	MAX.	Unit
VIN	Operating Input Voltage		4.5		30	V
l _{in}	VIN Consumption Current	VIN=30V, VFB=1.0V		0.5	1.0	mA
V _{UVLO1}	UVLO Detector Voltage	Falling		V _{UVLO2} -0.2		V
V_{UVLO2}	UVLO Released Voltage	Rising	3.7	4.0	4.2	V
VFB	FB Voltage Tolerance		0.788	0.800	0.812	V
$\Delta V_{\text{FB}} / \Delta T$	VFB Voltage Temperature Coefficient	-40°C ≤ Ta ≤ 85°C		±150		ppm/ºC
fosc	Oscillator Frequency		1000	1250	1500	kHz
\mathbf{f}_{FLB}	Fold back Frequency	VFB<0.56V		310		kHz
Maxduty	Oscillator Maximum. Duty Cycle			85		%
t _{MIN}	Minimum On Time			100		ns
tstart	Soft-start Time	V _{FB} =0.72V	0.2	0.4	0.6	ms
RLXH	Lx High Side Switch ON Resistance			0.35		Ω
	Lx High Side Switch Leakage Current			0	5	μA
ILIMLXH	Lx High Side Switch Limited Current			2.0		A
V_{CEH}	CE "H" Input Voltage		1.6			V
V_{CEL}	CE "L" Input Voltage				0.3	V
I _{FB}	VFB Input Current		-1.0		1.0	μA
ICEH	CE "H" Input Current		-1.0		1.0	μA
ICEL	CE "L" Input Current		-1.0		1.0	μA
T _{TSD}	Thermal Shutdown Detect Temperature	Hysteresis 30°C		160		°C
Istandby	Standby Current	V _{IN} =30V		0	5	μA

RECOMMENDED OPERATING CONDITIONS (ELECTRICAL CHARACTERISTICS)

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

TYPICAL APLICATION



(External Parts)

CIN	10µF KTS500B106M55N0T00 (Nippon Chemi-Con)
Соит	10μF GRM31CR71E106K (Murata)
CBST	0.1µF GRM21BB11H104KA01L (Murata)
L	4.7μH SLF7045T-4R7M2R0-PF (TDK)
D	MA24D60 (Panasonic)

• Technical Notes on External Components

External components must be connected as close as possible to the Ics and make wiring as short as possible. Especially, the capacitor connected in between V_{IN} and GND pin must be placed close to the IC.

If the impedance of power line and ground line is high, the internal voltage level may shift by the switching current and unstable operation may result. Make the power line and GND line sufficient. Step down regulator draws large current from the power supply and large switching current flows through the GND line, the inductor, Lx line, V_{OUT} line, therefore precaution for layout is necessary. Besides, the wiring between the divider resistor(R1) for setting output voltage and the inductor, and the wiring between the load and the inductor must be separated.

Ceramic capacitors have very low equivalent series resistance(ESR) and provide the best performance for the R1244N001B. Good values of C_{IN} capacitor between V_{IN} and GND is equal or more than 10µF, and good values of C_{OUT} capacitor is equal or more than 10µF if the output voltage, V_{OUT} \geq 1.8V. If the output voltage, V_{OUT} < 1.8V, equal or more than 20µF is recommended. Keep in mind that depending on the ceramic capacitor, the voltage bias characteristics and the temperature characteristics are different.

Select the inductor value in the range between 4.7μ H and 10μ H if the output voltage, $V_{OUT} \ge 5V$, 4.7μ H if the output voltage is $5V > V_{OUT} \ge 1.8V$, and 2.2μ H if the output voltage $V_{OUT} < 1.8V$. Phase compensation of this IC has been made according to the combination of these inductance values and C_{OUT} ceramic capacitor values. If the inductance value is smaller than the recommendation value, the over-current protection circuit may work by increasing the peak switching current at large load current.

Over-current protection circuit is influenced by self-heating of the IC by the operation and the condition of the heat radiation.

A Schottky diode is recommended for the catch diode. Choose the diode with small terminal capacitance, Ct. If Ct is too large, during the on time of switching, large switching current flows, and unstable operation may result.

Output voltage can be set according to the equation $V_{OUT}=V_{FB} \times (R1+R2)/R2$. If the values of R1 and R2 are large, the impedance of V_{FB} pin increases, and pickup noise may result. The recommendation value range of R2 is approximately between 1.2k Ω and 16k Ω . If the operation may be unstable, reduce the impedance of V_{FB} pin.

RICOH

Vout(V)	0.8	1	1.2	1.3	1.5	1.8~6	6~15
R1(kΩ)	0			=(Vоит / 0.	8 – 1) × 1.2	2	
R2(kΩ)	open	1.20	1.20	1.20	1.20	1.20	1.20
Cspd(pF)	open	3300	2200	1500	470	470	330
C ουτ(μ F)	22 × 2	10 × 2	10 × 2	10 × 2	10 × 2	10	10
L(µH)	2.2	2.2	2.2	2.2	2.2	4.7	10.0(4.7)

Recommended value for each output voltage

Recommended external Compornents

Symbol	Condition	Value	Parts Name	MFR	
CIN		10μF/50V	UMK325BJ106MM-T	TAIYO YUDEN	
		10μF/50V	KTS500B106M55N0T00	Nippon Chemi-Con	
Соит	Vout >10V	10µF/50V	UMK325BJ106MM-T	TAIYO YUDEN	
		10μF/50V	KTS500B106M55N0T00	Nippon Chemi-Con	
	10V> Vout >1.8V	10μF/25V	GRM31CR71E106K	muRata	
	Vout <1.8V	22µF/10V	GRM31CR71A226M	muRata	
			NOTE: The value of Cout depends upon the setting output voltage.		
CBST		0.1µF/50V	GRM21BB11H104KA01L	muRata	
RBST		47Ω			
L	40V/2.0A	10µH	SLF6045T-100M1R6-3PF	TDK	
		4.7μΗ	SLF7045T-4R7M2R0-PF	TDK	
·		2.2μH	VLCF4020T-2R2N1R7	TDK	
D	30V/2.0A	0.32V	CMS06	TOSHIBA	
	40V/2.0A	0.49V	CMS11	TOSHIBA	
	30V/1.5A	0.42V	MA22D28	Panasonic	
	40V/2.0A	0.43V	MA24D60	Panasonic	
			NOTE: Diode depends upon the input voltage and output Current.		
Rce	In the IC, ESD protection diode is connected between CE pin and V _{IN} pin. If there is a possibility that the CE pin voltage becomes higher than the V _{IN} pin voltage, it is recommended to insert a $4.7k\Omega$ resistance or more in order to prevent the large current flowing from CE pin into V _{IN} pin.				

*The performance of power circuit using those Ics extremely depends upon the peripheral circuits. Pay attention in the selection of the peripheral circuits. In particular, design the peripheral circuits in a way that the values such as voltage, current, and power of each component, PCB patterns and the IC do not exceed their respected rated values. (such as the voltage, current and power)

Operation of Step Converter and The Output Current

The DC/DC converter charges energy in the inductor when switch is ON, and discharges the energy from the inductor when switch is OFF and controls with less energy loss, so that a lower output voltage than the input voltage is obtained. The operation will be explained with reference to the following diagrams:

<Current through>

<Basic Circuits>



- Step 1: Switch turns on and current IL (=I1) flows, and energy is charged into Cout. At this moment, IL increases from Ilmin (=0) to reach Ilmax in proportion to the on-time period (ton) of Switch.
- Step 2: When Switch turns off, Synchronous rectifier Diode turns on in order that L maintains IL at Ilmax, and current IL (=I2) flows.
- Step 3: IL (=I2) decreases gradually and reaches IL=IImin=0 after a time period of topen, and Diode turns off. Provided that in the continuous mode, next cycle starts before IL becomes to 0 because toff time is not enough. In this case, IL value increases from this IImin (>0).

In the case of PWM control system, the output voltage is maintained by controlling the on-time period (ton), with the oscillator frequency (fosc) being maintained constant.

Output Current and Selection of External Components

The relation between the output current and external components is as follows:

When Switch of Lx is ON:

(Wherein, Ripple Current P-P value is described as I_{RP} , ON resistance of Switch and Diode of Lx are respectively described as R_{ONH} and V_F and the DC resistor of the inductor is described as R_{L} .)

VIN = VOUT + (RONH + RL) × IOUT + L × IRP / ton ······ Equation 1

When Switch is "OFF" (Diode is "ON") as toff:

 $L \times I_{RP}$ / toff = V_F + V_{OUT} + R_L × I_{OUT} ······Equation 2

Put Equation 2 to Equation 1 and solve for ON duty of Switch, ton / (toff + ton) = DON,

Don = (Vout + VF + RL × Iout)/(VIN + VF - RONH × Iout) ····· Equation 3

Ripple Current is as follows:

Wherein, peak current that flows through L, and Switch is as follows:

Ilmax = Iout + IRP / 2······Equation 5

Consider Ilmax, condition of input and output and select external components.

*The above explanation is directed to the calculation in an ideal case in continuous mode.



TYPICAL CHARACTERISTICS 1) Output Voltage VS. Output Current







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4) FB Voltage VS. Temperature R1244N001B



5) Oscillator Frequency VS. Temperature R1244N001B

6) Maxduty VS. Temperature R1244N001B







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